RECTRON SEMICONDUCTOR
TECHNICAL SPECIFICATION

HFM101 THRU HFM108

SURFACE MOUNT GLASS PASSIVATED HIGH EFFICIENCY SILICON RECTIFIER

VOLTAGE RANGE 50 to 1000 Volts CURRENT 1.0 Ampere

FEATURES

* Glass passivated device
* Ideal for surface mounted applications
* Low leakage current
* Metallurgically bonded construction
* Mounting position: Any
* Weight: 0.057 gram

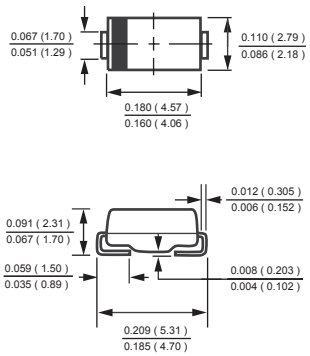
MECHANICAL DATA

* Epoxy: Device has UL flammability classification 94V-O

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

DO-214AC



Dimensions in inches and (millimeters)

MAXIMUM RATINGS (@ TA=25 °C unless otherwise noted)

RATINGS	SYMBOL	HFM101	HFM102	HFM103	HFM104	HFM105	HFM106	HFM107	HFM108	UNITS
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	300	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	210	280	420	490	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	300	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at T_A = 50°C	I_O	1.0								Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	30								Amps
Typical Thermal Resistance (Note 1)	$R_{\theta JL}$	27								°C/W
Typical Thermal Resistance (Note 1)	$R_{\theta JA}$	75								°C/W
Typical Junction Capacitance (Note 2)	C_J	15					12			pF
Operating Temperature Range	T_J	150								°C
Storage Temperature Range	T_{STG}	-55 to + 150								°C

ELECTRICAL CHARACTERISTICS(@TA=25 °C unless otherwise noted)

CHARACTERISTICS		SYMBOL	HFM101	HFM102	HFM103	HFM104	HFM105	HFM106	HFM107	HFM108	UNITS
Maximum Instantaneous Forward Voltage at 1.0A DC		V_F	1.0			1.3		1.7			Volts
Maximum Full Load Reverse Current, Full cycle Average T_A =55°C		I_R	50								µA
Maximum Average Reverse Current	@T_A = 25°C		5								µA
at Rated DC Blocking Voltage	@T_A = 125°C		100								µA
Maximum Reverse Recovery Time (Note 4)		trr	50					75			nSec

NOTES : 1. Thermal Resistance : Mounted on PCB.
2. Measured at 1 MHz and applied reverse voltage of 4.0 volts.
3. "Fully ROHS compliant", "100% Sn plating (Pb-free)".
4. Test Conditions: I_F= 0.5A, I_R= -1.0A, I_{RR}= -0.25A.

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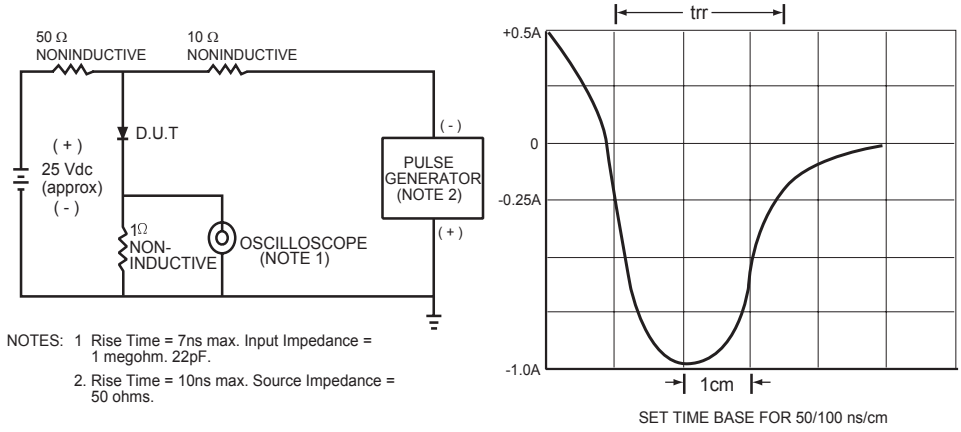
RATING AND CHARACTERISTICS CURVES (HFM101 THRU HFM108)



NOTES: 1 Rise Time = 7ns max. Input Impedance = 1 megohm. 22pF.

2. Rise Time = 10ns max. Source Impedance = 50 ohms.

FIG.1 TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

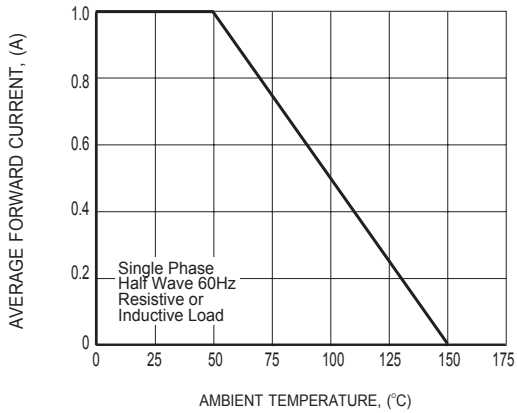


FIG.2 TYPICAL FORWARD CURRENT DERATING CURVE

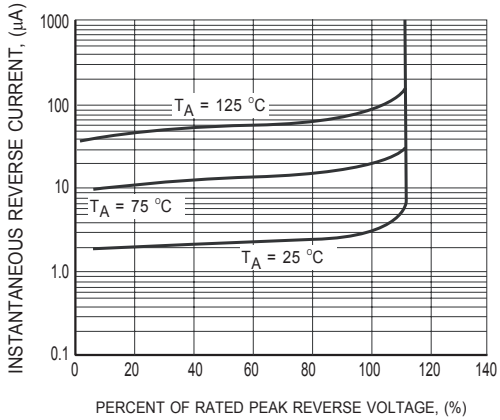


FIG.3 TYPICAL REVERSE CHARACTERISTICS

RATING AND CHARACTERISTICS CURVES (HFM101 THRU HFM108)

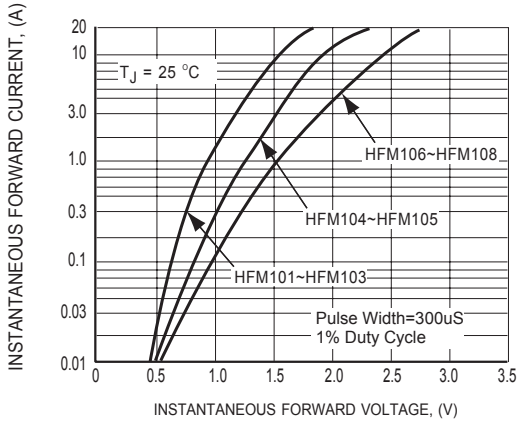


FIG.4 TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

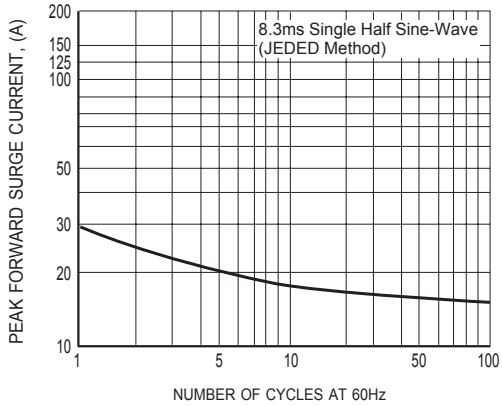


FIG.5 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

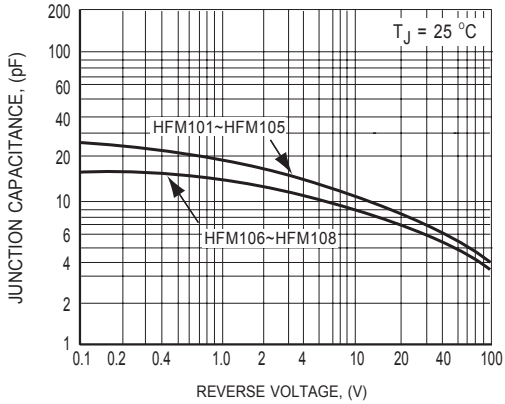
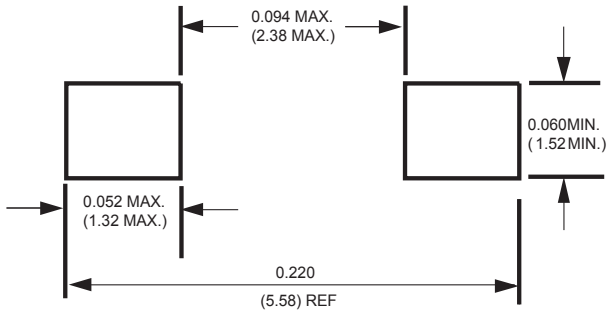


FIG.6 TYPICAL JUNCTION CAPACITANCE

Mounting Pad Layout



Dimensions in inches and (millimeters)

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